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## INFORMATION DISCLOSURE STATEMENT BY APPLICANT

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heet	1	of	2

Complete if Known				
Application Number	10/616,603			
Filing Date	10 July 2003			
First Named Inventor	Christophe Pierrat et al.			
Group Art Unit				
Examiner Name				
Attorney Docket Number	FTIS 1001-1			

	U.S. PATENT DOCUMENTS						
Examiner initials	Cite No.1	U.S. Patent Docume:  Kind Co Number  (# know	Name of Patentee or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YYYY	Pages, Cotumns, Lines, Where Relevant Passages or Relevant Figures Appear		
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	A15						
	A16						
	A17						
	A18						
	A19						
	A20						

	FOREIGN PATENT DOCUMENTS							
Examiner	Examiner Cite	Foreign Patent Document			Name of Patentee or	Date of Publication of	Pages, Columns, Lines,	
Initials*	No.1	Office <sup>3</sup>	Number <sup>4</sup>	Kind Code <sup>s</sup> (if known)	Applicant of Cited Document	Cited Document MM-DD-YYYY	Where Relevant Passages or Relevant Figures Appear	Тв
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<sup>1</sup> Unique citation designation number. 2 See attached Kinds of U.S. Patent Documents. 3 Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). <sup>4</sup> For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. <sup>5</sup> Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST. 16 if possible. Applicant is to place a check mark here if English language Translation is attached.



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Filing Date	10 July 2003			
First Named Inventor	Christophe Pierrat et al.			
Group Art Unit				
Examiner Name				
Attorney Docket Number	FTIS 1001-1			

		OTHER PRIOR ART – NON PATENT LITERATURE DOCUMENTS	
Examiner initials*	Cite No.1	tricked name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T²
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Examiner	Labora Chaladeris	Date	09/30/05
Signature	AFRITAN CACAMO ASAND	Considered	10110

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